



#### 60V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C
001/	$23m\Omega$ @ $V_{GS} = 10V$	50A
60V	$28m\Omega @ V_{GS} = 4.5V$	45A

## **Description and Applications**

This new generation MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Power Management
- Driving Solenoids
- Motor Control

## **Features**

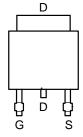
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMNH6021SK3Q)

### **Mechanical Data**

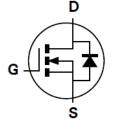
- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.33 grams (Approximate)



Top View



Pin Out Top View



**Equivalent Circuit** 

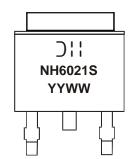
## Ordering Information (Note 4)

Part Number	Case	Packaging
DMNH6021SK3-13	TO252 (DPAK)	2,500/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



Oll = Manufacturer's Marking
NH6021S = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 16 = 2016)
WW = Week Code (01 to 53)



# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	$V_{DSS}$	60	V	
Gate-Source Voltage	$V_{GSS}$	±20	V	
Continuous Drain Current (Note 7) $V_{GS} = 10V$ $T_C = +25^{\circ}C$ $T_C = +100^{\circ}C$		ΙD	50 35	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	80	Α	
Maximum Continuous Body Diode Forward Current (Note 7)		Is	40	Α
Avalanche Current, L = 0.1mH (Note 8)		I <sub>AS</sub>	35	Α
Avalanche Energy, L = 0.1mH (Note 8)	E <sub>AS</sub>	64	mJ	

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		P <sub>D</sub>	2.1	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	73	°C/W
Total Power Dissipation (Note 6)		P <sub>D</sub>	3.7	W
Thermal Resistance, Junction to Ambient (Note 6)  Steady State		$R_{\theta JA}$	40	°C/W
Thermal Resistance, Junction to Case (Note 7)	R <sub>θ</sub> JC	1.8	°C/W	
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +175	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)	•				ı		
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	-	-	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	-	-	1	μA	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	-	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	-	3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance	D	-	13	23 mΩ	$V_{GS} = 10V, I_D = 12A$		
Static Dialit-Source Off-Resistance	R <sub>DS(ON)</sub>	-	18	28	11122	$V_{GS} = 4.5V, I_D = 12A$	
Diode Forward Voltage	$V_{SD}$	-	0.75	1.2	V	$V_{GS} = 0V, I_S = 20A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C <sub>iss</sub>	-	1143	-	pF		
Output Capacitance	Coss	-	168	-	pF	$V_{DS} = 25V, V_{GS} = 0V,$ -f = 1MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	1	69	-	pF	1 - 1101112	
Gate Resistance	$R_{g}$	1	2.5	-	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 10V)	$Q_g$	-	20.1	-	nC		
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	-	12.1	-	nC	7, , , , , , , , , , , , , , , , , , ,	
Gate-Source Charge	Q <sub>qs</sub>	-	4.3	-	nC	$V_{DS} = 30V, I_{D} = 20A$	
Gate-Drain Charge	Q <sub>gd</sub>	-	5.5	-	nC		
Turn-On Delay Time	t <sub>D(ON)</sub>	-	4.4	-	ns		
Turn-On Rise Time	t <sub>R</sub>	-	6.0	-	ns	$V_{DD} = 30V, V_{GS} = 10V,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	-	14.2	-	ns	$R_G = 4.7\Omega, I_D = 10A$	
Turn-Off Fall Time	t <sub>F</sub>	-	5.4	-	ns	7	
Reverse Recovery Time	t <sub>RR</sub>	-	21.2	_	ns	1 200 4:/-14 4000/	
Reverse Recovery Charge	$Q_{RR}$	-	- 15.2 - nC I <sub>F</sub> =20A, dl/dt=		I <sub>F</sub> =20A, di/dt=100A/μs		

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

<sup>6.</sup> Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

<sup>7.</sup> Thermal resistance from junction to soldering point (on the exposed drain pad).

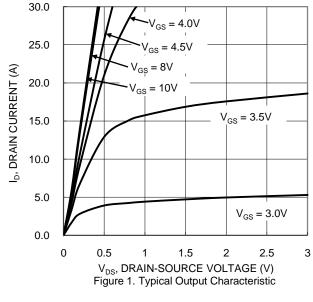
<sup>8.</sup>  $I_{AS}$  and  $E_{AS}$  ratings are based on low frequency and duty cycles to keep  $T_J$  = +25°C.

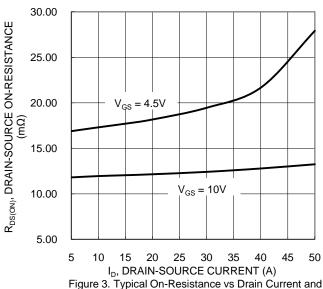
<sup>9.</sup> Short duration pulse test used to minimize self-heating effect.

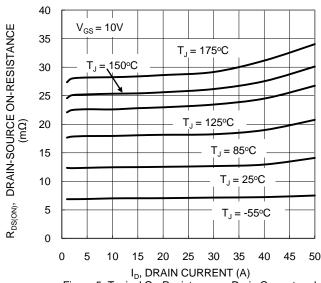
<sup>10.</sup> Guaranteed by design. Not subject to product testing.





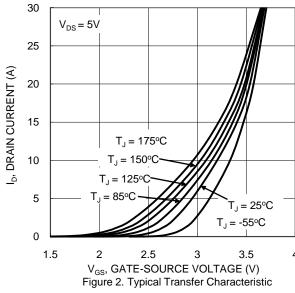


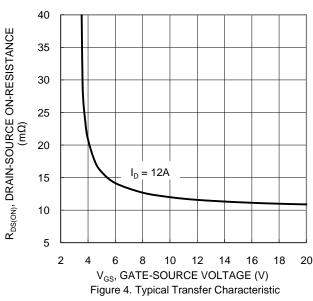




Gate Voltage

Figure 5. Typical On-Resistance vs Drain Current and Temperature





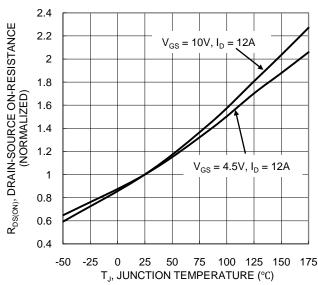
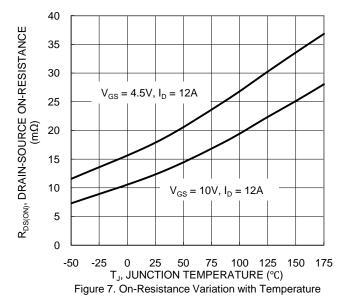
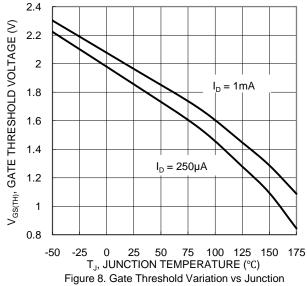


Figure 6. On-Resistance Variation with Temperature

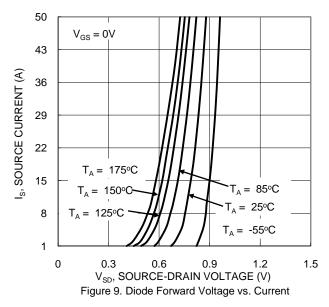


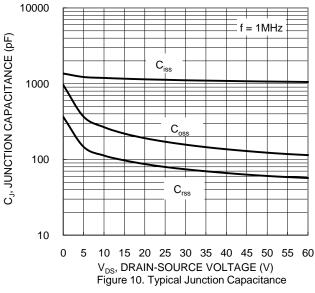


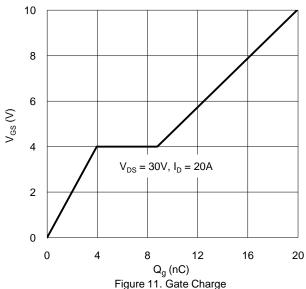


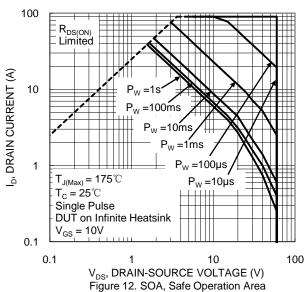


Temperature

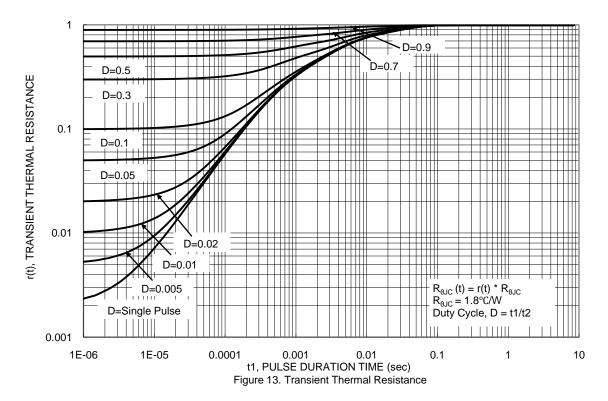










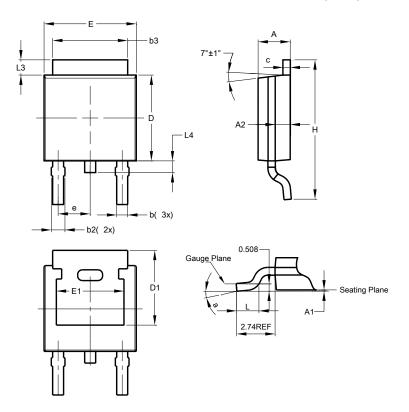




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### TO252 (DPAK)

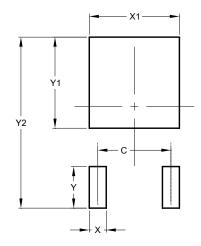


TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	-	-	2.286		
Е	6.45	6.70	6.58		
E1	4.32	-	-		
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	-		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### TO252 (DPAK)



Dimensions	Value (in mm)		
С	4.572		
Х	1.060		
X1	5.632		
Y	2.600		
Y1	5.700		
V2	10.700		



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